

## Improved Quad CMOS Analog Switches

### Features

- $\pm 22\text{-V}$  Supply Voltage Rating
- CMOS Compatible Logic
- Low On-Resistance— $r_{DS(on)}$ :  $45 \Omega$
- Low Leakage— $I_{D(on)}$ :  $20 \text{ pA}$
- Single Supply Operation Possible
- Extended Temperature Range
- Fast Switching— $t_{ON}$ :  $< 200 \text{ ns}$
- Low Glitching— $Q$ :  $1 \text{ pC}$

### Benefits

- Wide Analog Signal Range
- Simple Logic Interface
- Higher Accuracy
- Minimum Transients
- Reduced Power Consumption
- Superior to DG308A/309

### Applications

- Industrial Instrumentation
- Test Equipment
- Communications Systems
- Disk Drives
- Computer Peripherals
- Portable Instruments
- Sample-and-Hold Circuits

### Description

The DG308B/309B analog switches are highly improved versions of the industry-standard DG308A/309. These devices are fabricated in Siliconix' proprietary silicon gate CMOS process, resulting in lower on-resistance, lower leakage, higher speed, and lower power consumption.

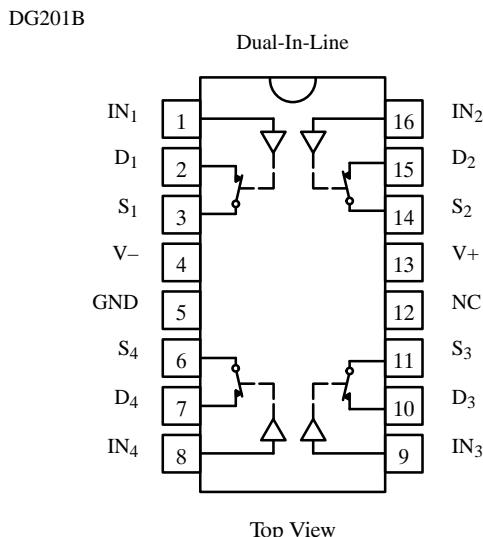
These quad single-pole single-throw switches are designed for a wide variety of applications in telecommunications, instrumentation, process control,

computer peripherals, etc. An improved charge injection compensation design minimizes switching transients. The DG308B and DG309B can handle up to  $\pm 22\text{-V}$  input signals. An epitaxial layer prevents latchup.

All devices feature true bi-directional performance in the on condition, and will block signals to the supply levels in the off condition.

The DG308B is a normally open switch and the DG309B is a normally closed switch. (See Truth Table.)

### Functional Block Diagram and Pin Configuration



Truth Table

Logic	DG308B	DG309B
0	OFF	ON
1	ON	OFF

Logic "0"  $\leq 3.5\text{V}$

Logic "1"  $\geq 11\text{ V}$

Switches Shown for Logic "0" Input

Ordering Information

Temp Range	Package	Part Number
-40 to $85^\circ\text{C}$	16-Pin Plastic DIP	DG308BDJ DG309BDJ
	16-Pin Narrow SOIC	DG308BDY DG309BDY
-55 to $125^\circ\text{C}$	16-Pin CerDIP	DG308BAK DG308BAK/883 DG309BAK DG309BAK/883

Updates to this data sheet may be obtained via facsimile by calling Siliconix FaxBack, 1-408-970-5600. Please request FaxBack document #70047.

## Absolute Maximum Ratings

Voltages Referenced to V<sub>-</sub>

V <sub>+</sub> .....	44 V
GND .....	25 V
Digital Inputs <sup>a</sup> V <sub>S</sub> , V <sub>D</sub> .....	(V <sub>-</sub> ) -2 V to (V <sub>+</sub> ) +2 V or 30 mA, whichever occurs first
Current, Any Terminal .....	30 mA

Peak Current, S or D

- a. Signals on S<sub>X</sub>, D<sub>X</sub>, or I<sub>NX</sub> exceeding V<sub>+</sub> or V<sub>-</sub> will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC Board.
- c. Derate 6.5 mW/<sup>o</sup>C above 75<sup>o</sup>C
- d. Derate 7.6 mW/<sup>o</sup>C above 75<sup>o</sup>C
- e. Derate 12 mW/<sup>o</sup>C above 75<sup>o</sup>C

(Pulsed at 1 ms, 10% duty cycle max) ..... 100 mA  
Storage Temperature (AK, Suffix) ..... -65 to 150<sup>o</sup>C  
(DJ, DY Suffix) ..... -65 to 125<sup>o</sup>C

Power Dissipation (Package)<sup>b</sup>

16-Pin Plastic DIP <sup>c</sup> .....	470 mW
16-Pin Narrow SOIC <sup>d</sup> .....	640 mW
16-Pin CerDIP <sup>e</sup> .....	900 mW

Notes:

## Specifications<sup>a</sup>

Parameter	Symbol	Test Conditions Unless Otherwise Specified  V <sub>+</sub> = 15 V, V <sub>-</sub> = -15 V V <sub>IN</sub> = 11 V, 3.5 V <sup>f</sup>	Temp  <sup>b</sup>	Typ <sup>c</sup>	A Suffix -55 to 125 <sup>o</sup> C		D Suffix -40 to 85 <sup>o</sup> C		Unit
					Min <sup>d</sup>	Max <sup>d</sup>	Min <sup>d</sup>	Max <sup>d</sup>	
<b>Analog Switch</b>									
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full		-15	15	-15	15	V
Drain-Source On-Resistance	R <sub>DS(on)</sub>	V <sub>D</sub> = ± 10 V, I <sub>S</sub> = 1 mA	Room Full	45		85 100		85 100	Ω
R <sub>DS(on)</sub> Match	ΔR <sub>DS(on)</sub>		Room	2					%
Source Off Leakage Current	I <sub>S(off)</sub>	V <sub>S</sub> = ± 14 V, V <sub>D</sub> = ± 14 V	Room Full	± 0.01	-0.5 -20	0.5 20	-0.5 -5	0.5 5	nA
Drain Off Leakage Current	I <sub>D(off)</sub>	V <sub>D</sub> = ± 14 V, V <sub>S</sub> = ± 14 V	Room Full	± 0.01	-0.5 -20	0.5 20	-0.5 -5	0.5 5	
Drain On Leakage Current	I <sub>D(on)</sub>	V <sub>S</sub> = V <sub>D</sub> = 14 V	Room Full	± 0.02	-0.5 -40	0.5 40	-0.5 -10	0.5 10	
<b>Digital Control</b>									
Input Voltage High	V <sub>INH</sub>		Full		11		11		V
Input Voltage Low	V <sub>INL</sub>		Full			3.5		3.5	
Input Current	I <sub>INH</sub> or I <sub>INL</sub>	V <sub>INH</sub> or V <sub>INL</sub>	Full		-1	1	-1	1	μA
Input Capacitance	C <sub>IN</sub>		Room	5					pF
<b>Dynamic Characteristics</b>									
Turn-On Time	t <sub>ON</sub>	V <sub>S</sub> = 3 V, See Figure 2	Room			200		200	ns
Turn-Off Time	t <sub>OFF</sub>		Room			150		150	
Charge Injection	Q	C <sub>L</sub> = 1000 pF, V <sub>g</sub> = 0 V, R <sub>g</sub> = 0 Ω	Room	1					pC
Source-Off Capacitance	C <sub>S(off)</sub>	V <sub>S</sub> = 0 V, f = 1 MHz	Room	5					pF
Drain-Off Capacitance	C <sub>D(off)</sub>		Room	5					
Channel On Capacitance	C <sub>D(on)</sub>	V <sub>D</sub> = V <sub>S</sub> = 0 V, f = 1 MHz	Room	16					dB
Off Isolation	OIRR	C <sub>L</sub> = 15 pF, R <sub>L</sub> = 50 Ω V <sub>S</sub> = 1 V <sub>RMS</sub> , f = 100 kHz	Room	90					
Channel-to-Channel Crosstalk	X <sub>TALK</sub>		Room	95					

## Specifications<sup>a</sup>

Parameter	Symbol	Test Conditions Unless Otherwise Specified  $V_+ = 15 \text{ V}$ , $V_- = -15 \text{ V}$ $V_{IN} = 11 \text{ V}, 3.5 \text{ V}^f$	Temp <sup>b</sup>	Typ <sup>c</sup>	A Suffix -55 to 125°C		D Suffix -40 to 85°C		Unit
					Min <sup>d</sup>	Max <sup>d</sup>	Min <sup>d</sup>	Max <sup>d</sup>	
<b>Power Supply</b>									
Positive Supply Current	I+	$V_{IN} = 0 \text{ or } 15 \text{ V}$	Room Full			1 5		1 5	μA
Negative Supply Current	I-		Room Full		-1 -5		-1 -5		
Power Supply Range for Continuous Operation	V <sub>OP</sub>		Full		±4	±22	±4	±22	V

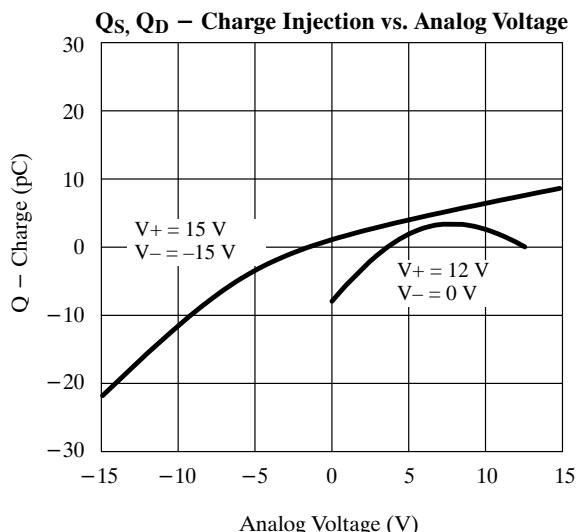
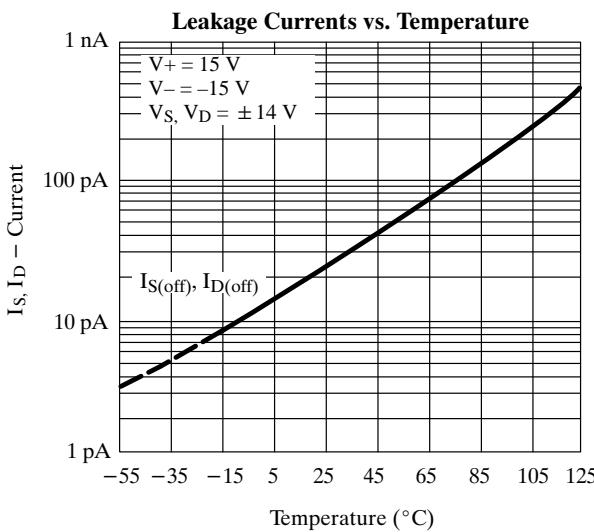
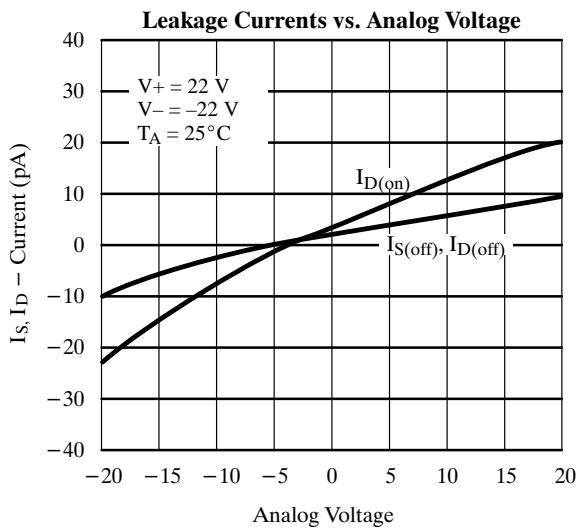
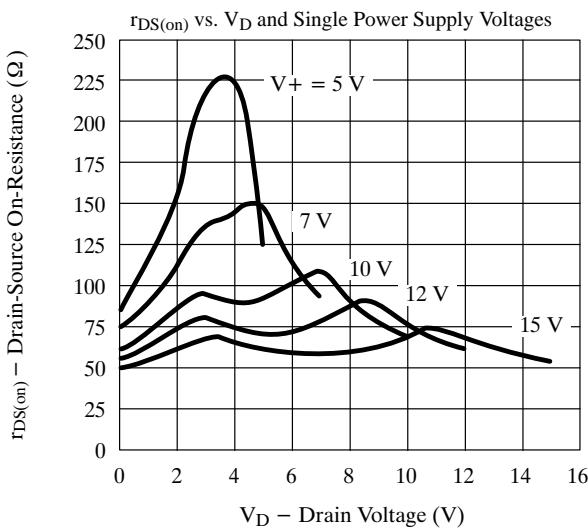
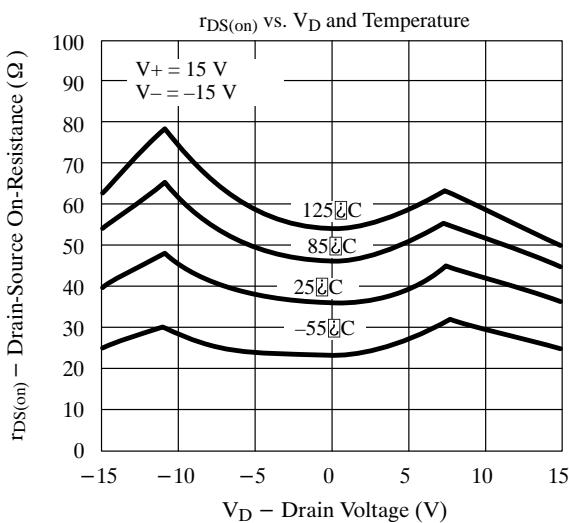
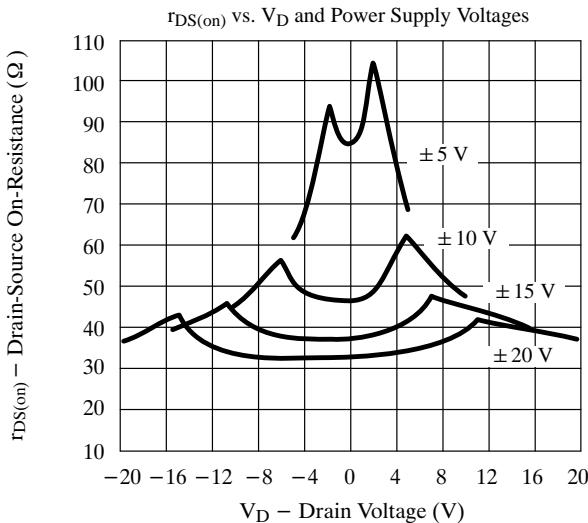
## Specifications<sup>a</sup> for Single Supply

Parameter	Symbol	Test Conditions Unless Otherwise Specified  $V_+ = 12 \text{ V}$ , $V_- = 0 \text{ V}$ $V_{IN} = 11 \text{ V}, 3.5 \text{ V}^f$	Temp <sup>b</sup>	Typ <sup>c</sup>	A Suffix -55 to 125°C		D Suffix -40 to 85°C		Unit
					Min <sup>d</sup>	Max <sup>d</sup>	Min <sup>d</sup>	Max <sup>d</sup>	
<b>Analog Switch</b>									
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>	$V_D = 3 \text{ V}, 8 \text{ V}, I_S = 1 \text{ mA}$	Full		0	12	0	12	V
Drain-Source On-Resistance	r <sub>D(on)</sub>		Room Full	90		160 200		160 200	Ω
<b>Dynamic Characteristics</b>									
Turn-On Time	t <sub>ON</sub>	$V_S = 8 \text{ V}$ , See Figure 2	Room			300		300	ns
Turn-Off Time	t <sub>OFF</sub>		Room			200		200	
Charge Injection	Q	C <sub>L</sub> = 1 nF, V <sub>gen</sub> = 6 V, R <sub>gen</sub> = 0 Ω	Room	4					pC
<b>Power Supply</b>									
Positive Supply Current	I+	$V_{IN} = 0 \text{ or } 12 \text{ V}$	Room Full			1 5		1 5	μA
Negative Supply Current	I-		Room Full		-1 -5		-1 -5		
Power Supply Range for Continuous Operation	V <sub>OP</sub>		Full		4	44	4	44	V

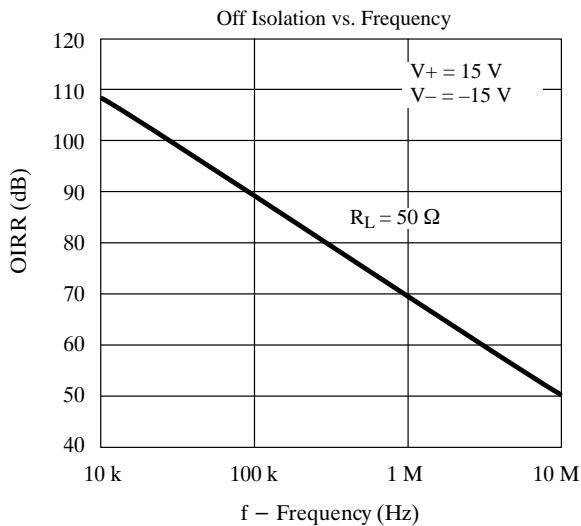
Notes:

- a. Refer to PROCESS OPTION FLOWCHART (Section 5 of the 1994 Data Book or FaxBack number 7103).
- b. Room = 25°C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.
- f. V<sub>IN</sub> = input voltage to perform proper function.

## Typical Characteristics



## Typical Characteristics (Cont'd)



## Schematic Diagram (Typical Channel)

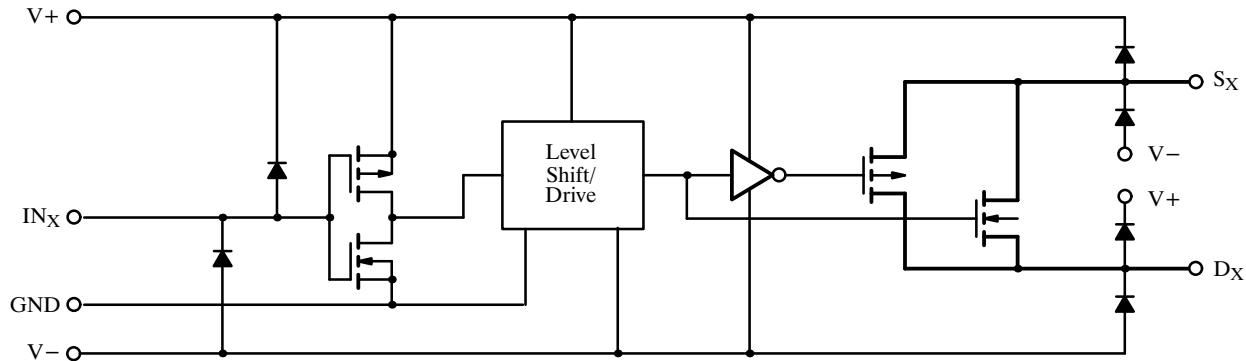


Figure 1.

## Test Circuits

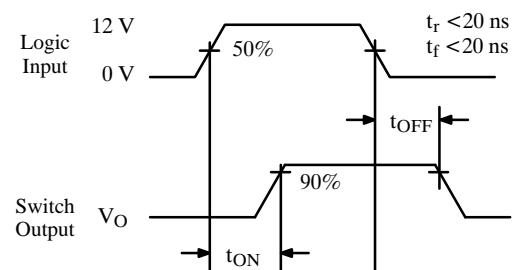
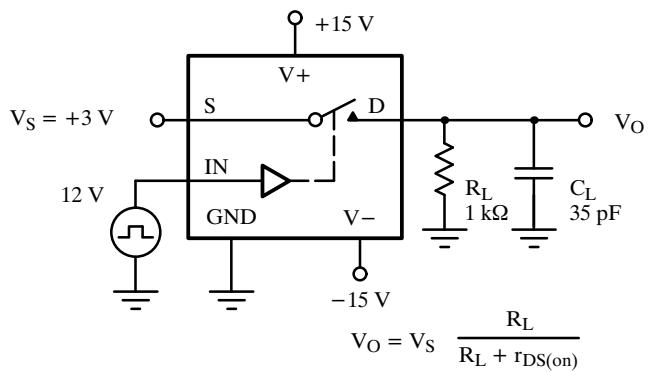


Figure 2. Switching Time

## Test Circuits (Cont'd)

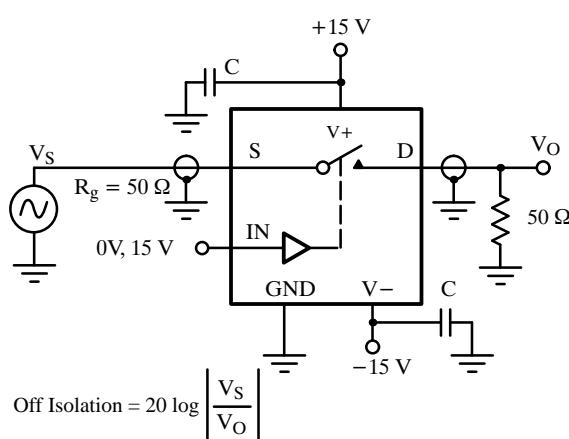


Figure 3. Off Isolation

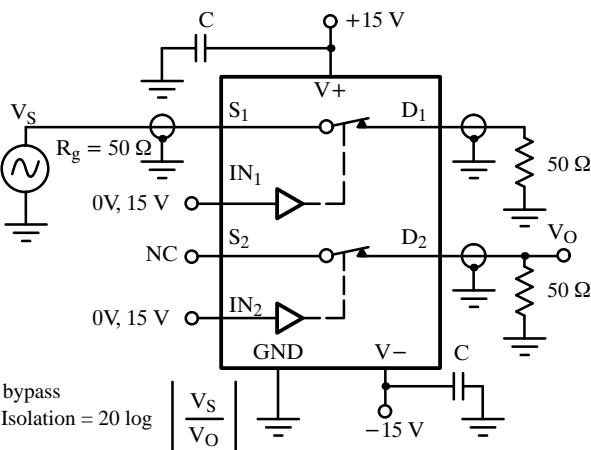


Figure 4. Channel-to-Channel Crosstalk

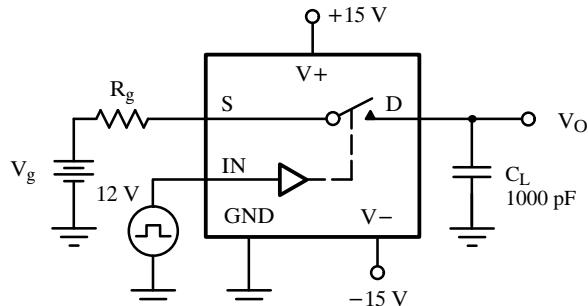
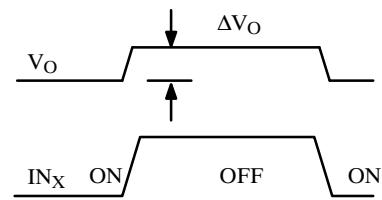


Figure 5. Charge Injection



$\Delta V_O$  = measured voltage error due to charge injection  
The charge injection in coulombs is  $Q = C_L \times \Delta V_O$

## Applications

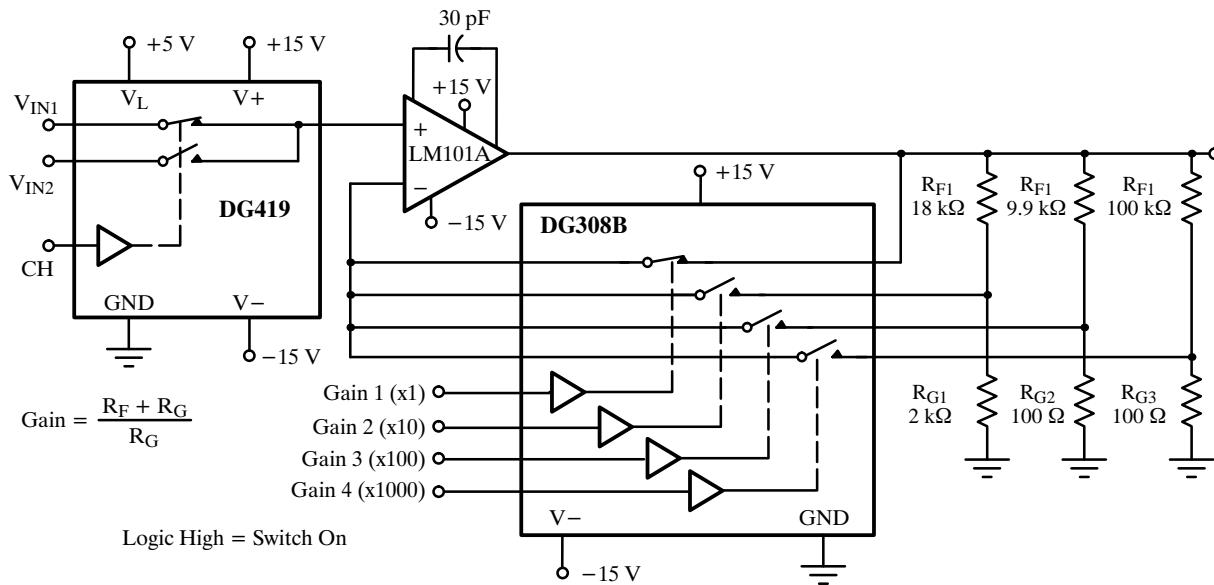


Figure 6. A Precision Amplifier with Digitally Programmable Inputs and Gains

## Applications (Cont'd)

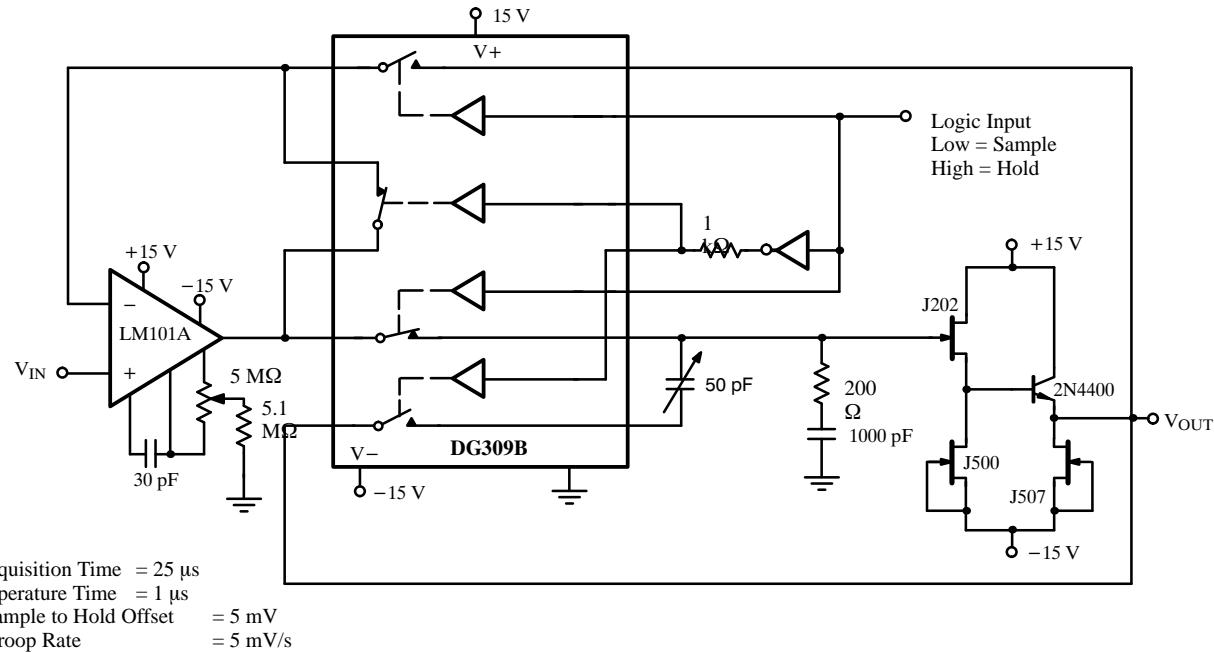


Figure 7. Sample-and-Hold

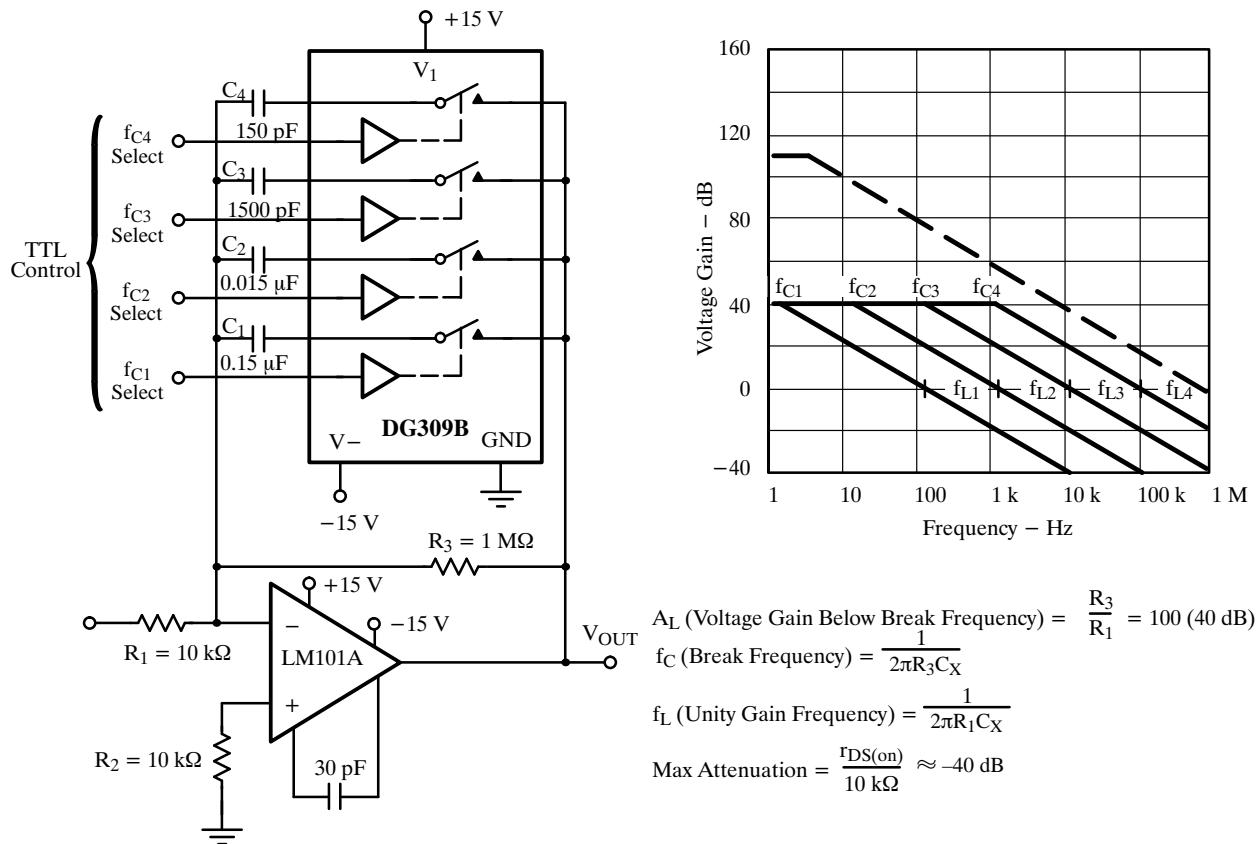


Figure 8. Active Low Pass Filter with Digitally Selected Break Frequency